Power MOSFET

72 A, 25 V, N-Channel DPAK

Features

- Planar HD3e Process for Fast Switching Performance
- Low R_{DS(on)} to Minimize Conduction Loss
- Low C_{ISS} to Minimize Driver Loss
- Low Gate Charge
- Pb-Free Packages are Available

MAXIMUM RATINGS (T_J = 25°C Unless otherwise specified)

Symbol	Value	Unit		
V _{DSS}	25	V_{dc}		
V _{GS}	±20	V_{dc}		
${\sf R}_{ heta JC} {\sf P}_{\sf D}$	2.4 62.5	°C/W W		
I _D I _D I _{DM}	72.0 62.8 32 140	A A A A		
R_{\thetaJA}	80	°C/W		
P _D I _D	1.87 12.0	W A		
R_{\thetaJA}	110	°C/W		
P _D I _D	1.36 10.0	W A		
T _J , T _{stg}	-55 to 175	°		
E _{AS}	71.7	mJ		
ΤL	260	°C		
	$\begin{array}{c} V_{DSS} \\ V_{GS} \\ R_{\theta JC} \\ P_D \\ I_D \\ I_D \\ I_D \\ I_D \\ I_D \\ I_D \\ R_{\theta JA} \\ P_D \\ I_D \\ I_D \\ T_J, T_{stg} \\ \hline \\ E_{AS} \end{array}$	Symbol Value V _{DSS} 25 V _{GS} ±20 R _{θJC} 2.4 PD 62.5 ID 72.0 ID 70.0 R _{0JA} 80 PD 1.36 ID 1.00 TJ, Tstg -55 to EAS 71.7		

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. When surface mounted to an FR4 board using 0.5 sq. in. pad size.

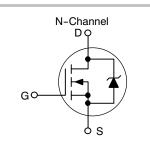
When surface mounted to an FR4 board using minimum recommended pad size.



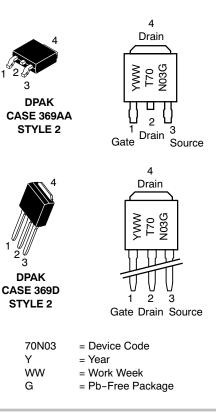
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V _{(BR)DSS}	R _{DS(on)} TYP	I _D MAX
25 V	$5.6~\mathrm{m}\Omega$	72 A







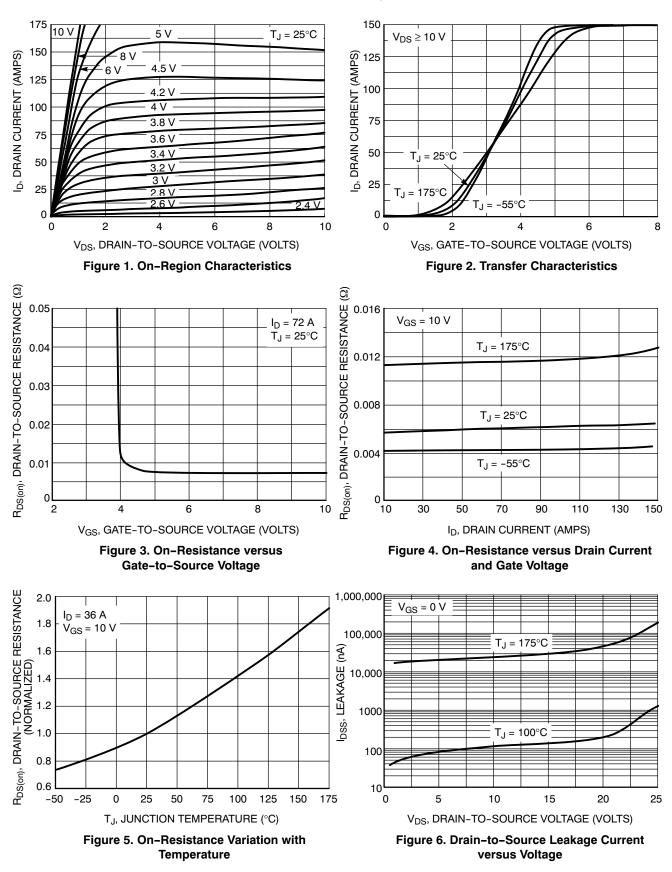
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

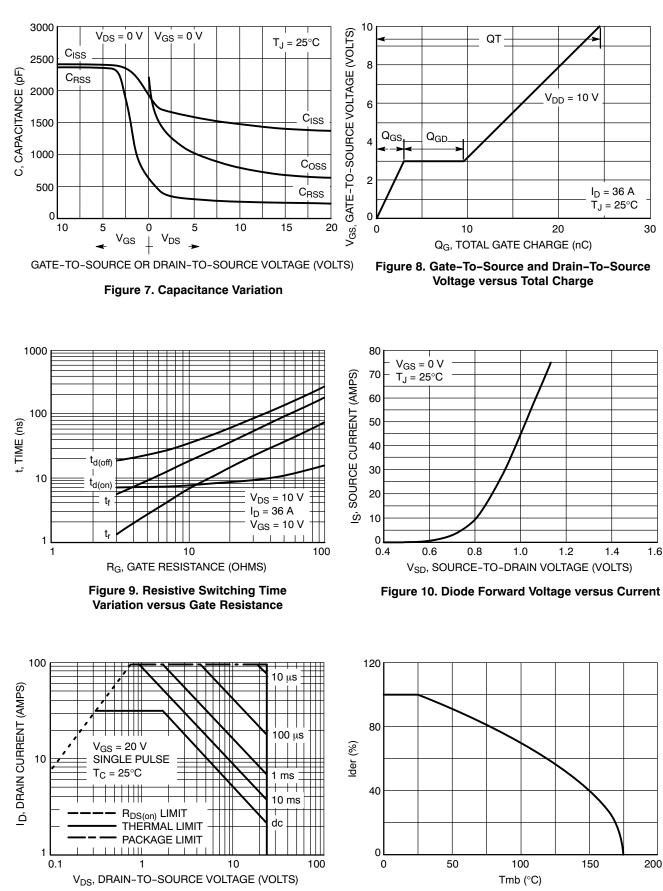
ELECTRICAL CHARACTERISTICS (T_J = 25° C Unless otherwise specified)

(Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS		-	-	-	-	
Drain-to-Source Breakdown Voltage (Note 3) $(V_{GS} = 0 V_{dc}, I_D = 250 \mu A_{dc})$ Temperature Coefficient (Positive)		V _{(br)DSS}	25 -	28 20.5		V _{dc} mV/°C
Zero Gate Voltage Drain Current $(V_{DS} = 20 V_{dc}, V_{GS} = 0 V_{dc})$ $(V_{DS} = 20 V_{dc}, V_{GS} = 0 V_{dc}, T_J = 150^{\circ}C)$		I _{DSS}	-		1.5 10	μA _{dc}
Gate-Body Leakage Current ($V_{GS} = \pm 20 V_{dc}, V_{DS} = 0 V_{dc}$		I _{GSS}	-	-	±100	nA _{dc}
ON CHARACTERISTICS (No	ote 3)					
Gate Threshold Voltage (Note 3) ($V_{DS} = V_{GS}$, $I_D = 250 \ \mu A_{dc}$) Threshold Temperature Coefficient (Negative)		V _{GS(th)}	1.0 -	1.5 4.0	2.0	V _{dc} mV/°C
Static Drain-to-Source On-Resistance (Note 3) ($V_{GS} = 4.5 V_{dc}$, $I_D = 20 A_{dc}$) ($V_{GS} = 10 V_{dc}$, $I_D = 20 A_{dc}$)		R _{DS(on)}		8.1 5.6	13 8.0	mΩ
Forward Transconductance ($(V_{DS} = 10 V_{dc}, I_D = 15 A_d)$		9 FS	-	27	-	Mhos
DYNAMIC CHARACTERIST	ICS					
Input Capacitance		C _{ISS}	-	1333	-	pF
Output Capacitance	$(V_{DS} = 20 V_{dc}, V_{GS} = 0 V, f = 1 MHz)$	C _{OSS}	-	600	-	
Transfer Capacitance	· · · · · · · · · · · · · · · · · · ·	C _{RSS}	-	218	-	
SWITCHING CHARACTERIS	STICS (Note 4)					
Turn-On Delay Time		t _{d(on)}	-	6.9	-	ns
Rise Time	(V _{GS} = 10 V _{dc} , V _{DD} = 10 V _{dc} ,	t _r	-	1.3	-	
Turn-Off Delay Time	$I_D = 36 A_{dc}, R_G = 3 \Omega$	t _{d(off)}	-	18.4	-	
Fall Time		t _f	-	5.5	-	
Gate Charge		QT	-	13.2	-	nC
	$(V_{GS} = 5 V_{dc}, I_D = 36 A_{dc}, V_{DS} = 10 V_{dc})$ (Note 3)	Q _{GS}	-	3.3	-	
		Q _{DS}	-	6.5	-	
SOURCE-DRAIN DIODE CH	IARACTERISTICS	-	-	-	-	
Forward On-Voltage	$ (I_S = 20 \ A_{dc}, \ V_{GS} = 0 \ V_{dc}) \ (Note \ 3) \\ (I_S = 20 \ A_{dc}, \ V_{GS} = 0 \ V_{dc}, \ T_J = 125^\circ C) $	V _{SD}	-	0.86 0.73	1.2 -	V _{dc}
Reverse Recovery Time		t _{rr}	-	27.9	-	ns
	<i>"</i>	t _a	-	14.8	-	1
	$(I_{S} = 36 A_{dc}, V_{GS} = 0 V_{dc}, dI_{S}/dt = 100 A/\mu s)$ (Note 3)	t _b	-	13.1	-	1
Reverse Recovery Stored Charge	1	Q _{RR}	-	19	-	nC

Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2%.
 Switching characteristics are independent of operating junction temperatures.

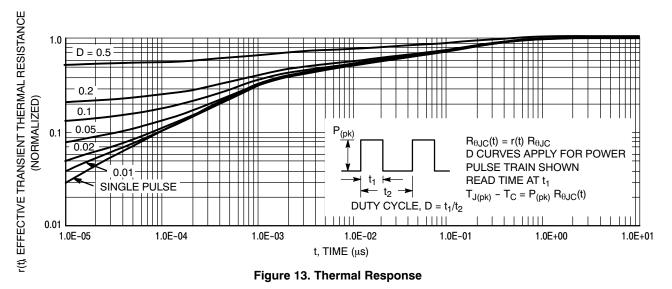


TYPICAL PERFORMANCE CURVES (T_J = 25° C unless otherwise noted)







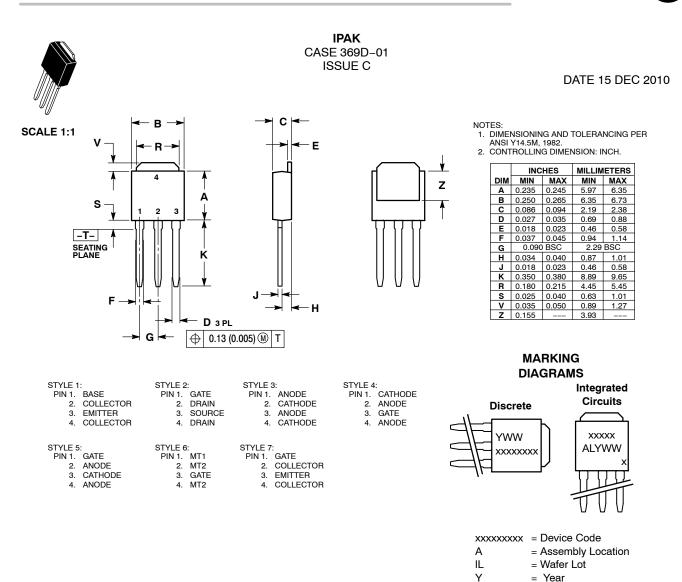


ORDERING INFORMATION

Order Number	Package	Shipping [†]	
NTD70N03R	DPAK-3	75 Units / Rail	
NTD70N03RG	DPAK-3 (Pb-Free)	75 Units / Rail	
NTD70N03RT4	DPAK-3	2500 / Tape & Reel	
NTD70N03RT4G	DPAK-3 (Pb-Free)	2500 / Tape & Reel	
NTD70N03R-1	DPAK-3 Straight Lead	75 Units / Rail	
NTD70N03R-1G	DPAK-3 Straight Lead (Pb-Free)	75 Units / Rail	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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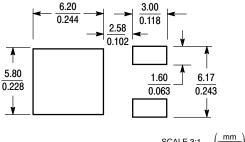
= Work Week

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1

L3

L4



*For additional information on our Pb-Free strategy and soldering

SCALE 3:1

Inches

details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DATE 03 JUN 2010

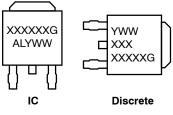
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

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- 2. CONTROLLING DIMENSION: INCHES. 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-
- THERMAL FAD CONTOR OF FIGURE WITHIN DEMONSIONS b3, L3 and Z.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL
- NOT EXCEED 0.006 INCHES PER SIDE 5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- 6. DATUMS A AND B ARE DETERMINED AT DATUM

	INCHES		MILLIMETER	
DIM	MIN	MAX	MIN	MAX
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
q	0.025	0.035	0.63	0.89
b2	0.030	0.045	0.76	1.14
b3	0.180	0.215	4.57	5.46
c	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
Е	0.250	0.265	6.35	6.73
е	0.090 BSC		2.29 BSC	
Н	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.108 REF		2.74 REF	
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Ζ	0.155		3.93	

MARKING DIAGRAM*



= Device Code = Assembly Location L = Wafer Lot Y = Year = Work Week WW G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking.

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